Reference Design

## TS3A24159 0.3- $\Omega$ 2-channel SPDT Bidirectional Analog Switch Dual-channel 2:1 Multiplexer and Demultiplexer

## 1 Features

- Specified break-before-make switching
- Low ON-state resistance ( $0.3 \Omega$ max)
- Low charge injection
- Excellent ON-state resistance matching
- Low total harmonic distortion (THD)
- $1.65-\mathrm{V}$ to $3.6-\mathrm{V}$ Single-supply operation
- Control inputs are 1.8 -V logic compatible
- Latch-up performance exceeds 100 mA per JESD 78, class II
- ESD Performance tested per JESD 22
- 2000-V Human-body model
(A114-B, Class II)
- 1000-V Charged-device model (C101)


## 2 Applications

- Cell phones
- Personal digital assistant (PDAs)
- Portable instrumentation
- Audio and video signal routing
- Low-voltage data-acquisition systems
- Communication circuits
- Modems
- Hard drives
- Computer peripherals
- Wireless terminals and peripherals


## 3 Description

The TS3A24159 is a 2 -channel single-pole doublethrow (SPDT) bidirectional analog switch that is designed to operate from 1.65 V to 3.6 V . It offers low ON -state resistance and excellent ON -state resistance matching with the break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another. The device has excellent total harmonic distortion (THD) performance, low ON-state resistence, and consumes very low power. These are some of the features that make this device suitable for a variety of markets and many different applications.

| Device Information $^{(1)}$ |  |
| :--- | :---: |
| PART NUMBER PACKAGE BODY SIZE (NOM) <br> TS3A24159 VSSOP (10) $3.00 \mathrm{~mm} \times 3.00 \mathrm{~mm}$ <br>  VSON $(10)$ $3.00 \mathrm{~mm} \times 3.00 \mathrm{~mm}$ <br>  DSBGA $(10)$ $1.86 \mathrm{~mm} \times 1.35 \mathrm{~mm}$ |  |

(1) For all available packages, see the orderable addendum at the end of the data sheet.


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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.
Changes from Revision E (March 2019) to Revision F Page

- Changed the YZP package image view From: Top-Through View To: Bottom View ..... 4
Changes from Revision D (July 2015) to Revision E Page
- Changed the YZP Package image and deleted the YZP Package Terminal Assignments table ..... 4
- Changed Turnon time $\mathrm{V}_{\mathrm{CC}}$ (Full) value From: 2.3 V to 2.7 V To: 2.7 V to 3.6 V in Switching Characteristics for a 3-V Supply ..... 10
- Changed Turnon time $\mathrm{V}_{\mathrm{CC}}$ (Full) value From: 2.3 V to 2.7 V To: 2.7 V to 3.6 V in Switching Characteristics for a 2.5- $\checkmark$ Supply ..... 10
Changes from Revision C (February 2008) to Revision D Page
- Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section ..... 1
- Changed $\mathrm{V}+$ to $\mathrm{V}_{\mathrm{CC}}$ throughout the document to meet JEDEC standards ..... 1


## 5 Pin Configuration and Functions



Pin Functions - VSSOP and VSON

| PIN |  | I/O |  |
| :--- | :---: | :---: | :--- |
| NO. | NAME |  |  |
| 1 | V | DESCRIPTION | - |

A


Pin Functions - DSBGA

| PIN |  | I/O |  |
| :--- | :---: | :---: | :--- |
| NO. | NAME |  |  |
| A1 | NC1 | I/O | Normally Closed Signal Path |
| A2 | GND | - | Ground |
| A3 | NC2 | I/O | Normally Closed Signal Path |
| B1 | IN1 | I | Digital Control to Connect COM to NO or NC |
| B3 | IN2 | I | Digital Control to Connect COM to NO or NC |
| C1 | COM1 | I/O | Common Signal Path |
| C3 | COM2 | I/O | Common Signal Path |
| D1 | NO1 | I/O | Normally Open Signal Path |
| D2 | VCC | - | Power Supply |
| D3 | NO2 | I/O | Normally Open Signal Path |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ${ }^{(1)}{ }^{(2)}$

|  |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage ${ }^{(3)}$ |  | -0.5 | 3.6 | V |
| $\begin{array}{\|l} \mathrm{V}_{\mathrm{NC}} \\ \mathrm{~V}_{\mathrm{NO}} \\ \mathrm{~V}_{\mathrm{COM}} \\ \hline \end{array}$ | Signal voltage ${ }^{(3)(4)}$ |  | -0.5 | $\mathrm{V}_{C C}+0.5$ | V |
| $\mathrm{I}_{\text {I/OK }}$ | Analog port diode current | $\mathrm{V}_{\mathrm{NC}}, \mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{COM}}<0$ | -50 | 50 | mA |
| $\mathrm{I}_{\mathrm{NC}}$ | ON-state switch current |  | -300 | 300 |  |
| $\begin{array}{\|l} \mathrm{I}_{\mathrm{NO}} \\ \mathrm{I}_{\mathrm{COM}} \end{array}$ | ON-state peak switch current ${ }^{(5)}$ | $\mathrm{V}_{\mathrm{NC}}, \mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{COM}}=0$ to $\mathrm{V}_{\mathrm{CC}}$ | -500 | 500 | mA |
| $\mathrm{V}_{\text {IN }}$ | Digital input voltage |  | -0.5 | 3.6 | V |
| $\mathrm{I}_{\mathrm{IK}}$ | Digital input clamp current ${ }^{(3)}$ | $V_{1}<0$ | -50 |  | mA |
| $\mathrm{I}_{\mathrm{CC}}$ | Continuous current through $\mathrm{V}_{\mathrm{CC}}$ |  |  | 100 | mA |
| $\mathrm{I}_{\text {GND }}$ | Continuous current through GND |  | -100 |  | mA |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(3) All voltages are with respect to ground, unless otherwise specified.
(4) This value is limited to 5.5 V maximum.
(5) Pulse at 1 -ms duration $<10 \%$ duty cycle

### 6.2 ESD Ratings

|  |  | VALUE | UNIT |
| :---: | :---: | :---: | :---: |
|  | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ${ }^{(1)}$ | 2000 |  |
| $\mathrm{V}_{\text {(ESD) }} \quad$ Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 or ANSI/ESDA/JEDEC JS-002 ${ }^{(2)}$ | 1000 | V |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|  |  | MIN | MAX | UNIT |
| :--- | :--- | ---: | :---: | :---: |
| $V_{C C}$ | Supply Voltage | 1.65 | 3.6 | V |
| $\mathrm{~V}_{\text {NC }}$ | Signal Voltage | 0 | $V_{C C}$ | V |
| $\mathrm{~V}_{\mathrm{NO}}$ |  |  |  |  |
| $\mathrm{V}_{\mathrm{COM}}$ |  | 0 | $\mathrm{~V}_{\mathrm{CC}}$ | V |
| $\mathrm{V}_{\mathrm{IN}}$ | Digital Input Voltage | 0 |  |  |

### 6.4 Thermal Information

| THERMAL METRIC ${ }^{(1)}$ |  | TS3A24159 |  |  | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | DGS (VSSOP) | DRC (VSON) | YZP (DSBGA) |  |
|  |  | 10 PINS | 10 PINS | 10 PINS |  |
| $\mathrm{R}_{\text {өJA }}$ | Junction-to-ambient thermal resistance | 154 | 49.4 | 90.9 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {өJC(top) }}$ | Junction-to-case (top) thermal resistance | 37.9 | 71.2 | 0.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\theta \mathrm{JB}}$ | Junction-to-board thermal resistance | 83.6 | 23.8 | 8.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| \%JT | Junction-to-top characterization parameter | 1.4 | 2.2 | 3.2 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\Psi_{\text {JB }}$ | Junction-to-board characterization parameter | 82.2 | 23.8 | 8.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\theta \mathrm{\theta CC} \text { (bot) }}$ | Junction-to-case (bottom) thermal resistance | N/A | 6.1 | N/A | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

### 6.5 Electrical Characteristics for 3-V Supply

$\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |  |  |  |  |
| Analog signal range | $\begin{gathered} \mathrm{V}_{\mathrm{COM}}, \mathrm{~V}_{\mathrm{NO}} \\ \mathrm{~V}_{\mathrm{NC}} \end{gathered}$ |  |  |  |  | 0 |  | $\mathrm{V}_{\mathrm{CC}}$ | V |
| Peak ON resistance | $\mathrm{r}_{\text {peak }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.2 | 0.3 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.35 |  |
| ON-state resistance | $r_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=2 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.26 | 0.3 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.34 |  |
| ON-state resistance match between channels | $\Delta r_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=2 \mathrm{~V}, 0.8 \mathrm{~V} \text {, } \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.01 | 0.05 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.05 |  |
| ON-state resistance flatness | $\mathrm{r}_{\text {on(flat) }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 2.7 V | 0.13 |  |  | $\Omega$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=2 \mathrm{~V}, 0.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-100 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ |  |  | 0.01 | 0.04 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.05 |  |
| NC, NO OFF leakage current | $\mathrm{I}_{\mathrm{NC}(\mathrm{OFF})}$, $\mathrm{I}_{\mathrm{NO}(\text { OFF })}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=3 \mathrm{~V}$, or $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=1 \mathrm{~V}$, | Switch OFF, <br> See Figure 11 | $25^{\circ} \mathrm{C}$ | 3.6 V | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -50 |  | 50 |  |
| NC, NO ON leakage current | $\mathrm{I}_{\mathrm{NC}(\mathrm{ON}),}$, $\mathrm{I}_{\mathrm{NO}(\mathrm{ON})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=$ Open, or $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=$ Open, | Switch ON, See Figure 12 | $25^{\circ} \mathrm{C}$ | 3.6 V | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -100 |  | 100 |  |
| COM ON leakage current | $\mathrm{I}_{\text {COM(ON }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\text { Open, } \mathrm{V}_{\mathrm{COM}}=1 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\text { Open, } \mathrm{V}_{\mathrm{COM}}=3 \mathrm{~V}, \end{aligned}$ | Switch ON, See Figure 12 | $25^{\circ} \mathrm{C}$ | 3.6 V | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -100 |  | 100 |  |

DIGITAL CONTROL INPUTS (IN1, IN2) ${ }^{(2)}$

| Input logic high | $\mathrm{V}_{\mathrm{IH}}$ |  | Full |  | 1.4 |  |  | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input logic low | $\mathrm{V}_{\mathrm{IL}}$ |  | Full |  |  |  | 0.5 | V |
| Input leakage current | $I_{\text {IH }}, I_{\text {IL }}$ | $\mathrm{V}_{\mathrm{I}}=3.6 \mathrm{~V}$ or 0 | $25^{\circ} \mathrm{C}$ | 3.6 V | -40 | 5 | 40 | nA |
|  |  |  | Full |  | -50 |  | 50 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at $\mathrm{V}_{\mathrm{Cc}}$ or GND to ensure proper device operation. Refer to the Tl application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## Electrical Characteristics for 3-V Supply (continued)

$\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{\mathrm{Cc}}$ | MIN TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC |  |  |  |  |  |  |  |  |
| Charge injection | $Q_{C}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF},$ <br> See Figure 19 | $25^{\circ} \mathrm{C}$ | 3 V | 9 |  | pC |
| NC, NO OFF capacitance | $\mathrm{C}_{\mathrm{NC} \text { (OFF) }}$, <br> $\mathrm{C}_{\mathrm{NO}(\mathrm{OFF})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}$ or GND , Switch OFF, | See Figure 13 | $25^{\circ} \mathrm{C}$ | 3 V | 90 |  | pF |
| NC, NO ON capacitance | $\mathrm{C}_{\mathrm{NC}(\mathrm{ON})}$, <br> $\mathrm{C}_{\mathrm{NO}(\mathrm{ON})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}$ or GND , Switch ON, | See Figure 13 | $25^{\circ} \mathrm{C}$ | 3 V | 224 |  | pF |
| COM ON capacitance | $\mathrm{C}_{\text {COM(ON) }}$ | $\mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}$ or GND, Switch ON, | See Figure 13 | $25^{\circ} \mathrm{C}$ | 3 V | 250 |  | pF |
| Digital input capacitance | $\mathrm{C}_{1}$ | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND, | See Figure 13 | $25^{\circ} \mathrm{C}$ | 3 V | 2 |  | pF |
| Bandwidth | BW | $\mathrm{R}_{\mathrm{L}}=50 \Omega,$ <br> Switch ON, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3 V | 23 |  | MHz |
| OFF isolation | OISO | $\begin{aligned} & R_{L}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | See Figure 17 | $25^{\circ} \mathrm{C}$ | 3 V | -72 |  | dB |
| Crosstalk | $\mathrm{X}_{\text {TALK }}$ | $\begin{aligned} & R_{L}=50 \Omega, \\ & f=1 \mathrm{MHz}, \end{aligned}$ | See Figure 18 | $25^{\circ} \mathrm{C}$ | 3 V | -96 |  | dB |
| Total harmonic distortion | THD | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \end{aligned}$ | $\begin{aligned} & f=20 \mathrm{~Hz} \text { to } \\ & 20 \mathrm{kHz}, \\ & \text { See Figure } 20 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3 V | 0.003\% |  |  |
| SUPPLY |  |  |  |  |  |  |  |  |
| Positive supply current | $\mathrm{I}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND |  | $25^{\circ} \mathrm{C}$ | 3.6 V | 15 | 100 | nA |
|  |  |  |  | Full |  | 1 |  | $\mu \mathrm{A}$ |

### 6.6 Electrical Characteristics for 2.5-V Supply

$\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |  |  |  |  |
| Analog signal range | $\begin{gathered} \mathrm{V}_{\mathrm{COM}}, \mathrm{~V}_{\mathrm{NO}} \\ \mathrm{~V}_{\mathrm{NC}} \end{gathered}$ |  |  |  |  | 0 |  | $\mathrm{V}_{\mathrm{Cc}}$ | V |
| Peak ON resistance | $\mathrm{r}_{\text {peak }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See <br> Figure 10 | $25^{\circ} \mathrm{C}$ | 2.3 V |  |  | 0.35 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.45 |  |
| ON-state resistance | $r_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=1.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 2.3 V |  |  |  | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.4 |  |
| ON-state resistance match between channels | $\Delta r_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=1.8 \mathrm{~V}, 0.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See <br> Figure 10 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 0.01 | 0.05 | $\Omega$ |
|  |  |  |  | Full |  |  | 0.05 | 0.05 |  |
| ON-state resistance flatness | $\mathrm{r}_{\text {on(flat) }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See <br> Figure 10 | $25^{\circ} \mathrm{C}$ | 2.3 V | 0.05 |  |  | $\Omega$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=0.8 \mathrm{~V}, 1.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See <br> Figure 10 | $25^{\circ} \mathrm{C}$ |  |  | 0.03 | 0.08 |  |
|  |  |  |  | Full |  |  |  | 0.1 |  |
| NC, NO OFF leakage current | $I_{\text {NC(OFF) }}$, $\mathrm{I}_{\mathrm{NO}(\mathrm{OFF})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=2.2 \mathrm{~V}$, or$\mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=2.2 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=0.5 \mathrm{~V} \text {, }$ | Switch OFF, See Figure 11 | $25^{\circ} \mathrm{C}$ | 2.7 V | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -50 |  | 50 |  |
| NC, NO ON leakage current | $\mathrm{I}_{\mathrm{NC}(\mathrm{ON})}$, $\mathrm{I}_{\mathrm{NO}(\mathrm{ON})}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=0.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=\text { Open, } \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=2.2 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=\text { Open, } \end{aligned}$ | Switch ON, See Figure 12 | $25^{\circ} \mathrm{C}$ | 2.7 V | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -100 |  | 100 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

## Electrical Characteristics for 2.5-V Supply (continued)

$V_{C C}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER | TEST CONDITIONS | TA | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH (continued) |  |  |  |  |  |  |
| COM <br> ON leakage <br> current $I_{\text {COM(ON }}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=$ Open, $\mathrm{V}_{\mathrm{COM}}=0.5 \mathrm{~V}$, Switch ON, <br> or See <br> $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=$ Open, $\mathrm{V}_{\mathrm{COM}}=2.2 \mathrm{~V}$, Figure 12 | $25^{\circ} \mathrm{C}$ Full | 2.7 V | -10 -100 | 10 100 | nA |

DIGITAL CONTROL INPUTS (IN1, IN2) ${ }^{(2)}$

| Input logic high | $\mathrm{V}_{\mathrm{IH}}$ |  | Full |  | 1.25 |  |  | V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input logic low | $\mathrm{V}_{\text {IL }}$ |  | Full |  |  |  | 0.5 | V |
| Input leakage current | $\mathrm{I}_{\mathrm{IH}}, \mathrm{I}_{\text {IL }}$ | $\mathrm{V}_{1}=2.7 \mathrm{~V}$ or 0 | $25^{\circ} \mathrm{C}$ | 2.7 V | -40 | 5 | 40 | nA |
|  |  |  | Full |  | -50 |  | 50 |  |

DYNAMIC

| Charge injection | $Q_{C}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=1 \mathrm{nF},$ <br> See <br> Figure 19 | $25^{\circ} \mathrm{C}$ | 2.5 V | 8 | pC |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| NC, NO OFF capacitance | $\mathrm{C}_{\mathrm{NC}(\mathrm{OFF})}$, $\mathrm{C}_{\mathrm{NO} \text { (OFF) }}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}$ or GND , Switch OFF, | See <br> Figure 13 | $25^{\circ} \mathrm{C}$ | 2.5 V | 90 | pF |
| NC, NO ON capacitance | $\mathrm{C}_{\mathrm{NC}(\mathrm{ON})}$, <br> $\mathrm{C}_{\mathrm{NO}(\mathrm{ON})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}$ or GND , Switch ON, | See <br> Figure 13 | $25^{\circ} \mathrm{C}$ | 2.5 V | 250 | pF |
| COM ON capacitance | $\mathrm{C}_{\text {Com(ON) }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}} \text { or GND, } \\ & \text { Switch ON, } \end{aligned}$ | See <br> Figure 13 | $25^{\circ} \mathrm{C}$ | 2.5 V | 250 | pF |
| Digital input capacitance | $\mathrm{C}_{1}$ | $\mathrm{V}_{1}=\mathrm{V}_{\mathrm{cc}}$ or GND, | See <br> Figure 13 | $25^{\circ} \mathrm{C}$ | 2.5 V | 2 | pF |
| Bandwidth | BW | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \text { Switch ON, } \end{aligned}$ | See <br> Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V | 23 | MHz |
| OFF isolation | OISO | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz}, \end{aligned}$ | See <br> Figure 17 | $25^{\circ} \mathrm{C}$ | 2.5 V | -72 | dB |
| Crosstalk | $\mathrm{X}_{\text {TALK }}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=1 \mathrm{MHz}, \end{aligned}$ | See <br> Figure 18 | $25^{\circ} \mathrm{C}$ | 2.5 V | -96 | dB |
| Total harmonic distortion | THD | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=600 \Omega, \\ & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \end{aligned}$ | $\begin{aligned} & \mathrm{f}=20 \mathrm{~Hz} \text { to } \\ & 20 \mathrm{kHz}, \\ & \text { See } \\ & \text { Figure } 20 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 2.5 V | 0.003\% |  |
| SUPPLY |  |  |  |  |  |  |  |
| Positive supply current | Icc | $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{C C}$ or GND |  | $25^{\circ} \mathrm{C}$ | 2.7 V | 10 | nA |
|  |  |  |  | Full |  | 700 |  |

(2) All unused digital inputs of the device must be held at $\mathrm{V}_{\mathrm{CC}}$ or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### 6.7 Electrical Characteristics for 1.8-V Supply

$\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | TA | $\mathrm{V}_{\mathrm{Cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH |  |  |  |  |  |  |  |  |  |
| Analog signal range | $\begin{gathered} \mathrm{V}_{\mathrm{COM}}, \mathrm{~V}_{\mathrm{NO}}, \\ \mathrm{~V}_{\mathrm{NC}} \end{gathered}$ |  |  |  |  | 0 |  | $\mathrm{V}_{\mathrm{CC}}$ | V |
| Peak ON resistance | $\mathrm{r}_{\text {peak }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{COM}}=-2 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 1.65 V |  | 0.4 | 0.7 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.8 |  |
| ON-state resistance | $\mathrm{r}_{\text {on }}$ | $\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=1.5 \mathrm{~V} \text {, }$$\mathrm{I}_{\mathrm{COM}}=-2 \mathrm{~mA},$ | Switch ON, <br> See Figure 10 | $25^{\circ} \mathrm{C}$ | 1.65 V |  | 0.3 | 0.45 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.5 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

## Electrical Characteristics for 1.8-V Supply (continued)

$\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | TA | $\mathrm{V}_{\mathrm{Cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ANALOG SWITCH (continued) |  |  |  |  |  |  |  |  |  |
| ON-state resistance match between channels | $\Delta r_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=0.6 \mathrm{~V}, 1.5 \mathrm{~V} \text {, } \\ & \mathrm{I}_{\mathrm{COM}}=-2 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 1.65 V |  | 0.02 | 0.04 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.05 |  |
| ON-state resistance flatness | $r_{\text {on(flat) }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq \mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{I}_{\mathrm{COM}}=-2 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ | 1.65 V | 0.13 |  |  | $\Omega$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=0.6 \mathrm{~V}, 1.5 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-8 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 10 | $25^{\circ} \mathrm{C}$ |  |  | 0.08 | 0.15 |  |
|  |  |  |  | Full |  |  |  | 0.2 |  |
| NC, NO OFF leakage current | $\mathrm{I}_{\mathrm{NC}(\mathrm{OFF})}$, $\mathrm{I}_{\mathrm{NO}(\mathrm{OFF})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=0.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=1.65 \mathrm{~V}$, or <br> $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1.65 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=0.3 \mathrm{~V}$, | Switch OFF, <br> See Figure 11 | $25^{\circ} \mathrm{C}$ | 1.95 | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -50 |  | 50 |  |
| NC, NO ON leakage current | $I_{\mathrm{NC}(\mathrm{ON})}$, $\mathrm{I}_{\mathrm{NO}(\mathrm{ON})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=0.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=$ Open, or <br> $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1.65 \mathrm{~V}, \mathrm{~V}_{\mathrm{COM}}=$ Open, | Switch ON, See Figure 12 | $25^{\circ} \mathrm{C}$ | 1.95 V | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -100 |  | 100 |  |
| COM ON leakage current | $\mathrm{I}_{\text {COM(ON) }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\text { Open, } \mathrm{V}_{\mathrm{COM}}=0.3 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NC}} \text { or } \mathrm{V}_{\mathrm{NO}}=\text { Open, } \mathrm{V}_{\mathrm{COM}}=1.65 \mathrm{~V}, \end{aligned}$ | Switch ON, See Figure 12 | $25^{\circ} \mathrm{C}$ | 1.95 V | -10 |  | 10 | nA |
|  |  |  |  | Full |  | -100 |  | 100 |  |

DIGITAL CONTROL INPUTS (IN1, IN2) ${ }^{(2)}$

(2) All unused digital inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

### 6.8 Switching Characteristics for a 3-V Supply

$\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | TA | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |  |
| Turnon time | $\mathrm{t}_{\mathrm{ON}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\begin{aligned} & C_{\mathrm{L}}=35 \mathrm{pF}, \\ & \text { See Figure } 14 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.0 V |  | 20 | 35 |  |
|  |  |  |  | Full | $\begin{gathered} 2.7 \mathrm{~V} \\ \text { to } \\ 3.6 \mathrm{~V} \end{gathered}$ |  |  | 40 | ns |
| Turnoff time | $\mathrm{t}_{\text {OFF }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 14 | $25^{\circ} \mathrm{C}$ | 3.0 V |  | 12 | 25 |  |
|  |  |  |  | Full | $\begin{gathered} 2.7 \mathrm{~V} \\ \text { to } \\ 3.6 \mathrm{~V} \end{gathered}$ |  |  | 30 | ns |
| Break-beforemake time | $t_{\text {BBM }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}}=\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 15 | $25^{\circ} \mathrm{C}$ | 3.0 V | 1 | 10 | 25 |  |
|  |  |  |  | Full | $\begin{gathered} 2.7 \mathrm{~V} \\ \text { to } \\ 3.6 \mathrm{~V} \\ \hline \end{gathered}$ | 0.5 |  | 30 | ns |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

### 6.9 Switching Characteristics for a 2.5-V Supply

$\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$

| PARAMETER |  | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |  |
| Turnon time | ton | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 23 | 45 | ns |
|  |  |  |  | Full | $\begin{gathered} 2.3 \mathrm{~V} \\ \text { to } \\ 2.7 \mathrm{~V} \end{gathered}$ |  |  | 50 |  |
| Turnoff time | toff | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 17 | 27 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.3 \mathrm{~V} \\ & \text { to } \\ & 2.7 \mathrm{~V} \end{aligned}$ |  |  | 30 |  |
| Break-beforemake time | $t_{\text {BBM }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}}=\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 15 | $25^{\circ} \mathrm{C}$ | 2.5 V | 2 | 14 | 30 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.3 \mathrm{~V} \\ & \text { to } \\ & 2.7 \mathrm{~V} \end{aligned}$ | 1 |  | 35 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

### 6.10 Switching Characteristics for a 1.8-V Supply

| $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted) ${ }^{(1)}$ |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | TEST CONDITIONS |  | $\mathrm{T}_{\text {A }}$ | $\mathrm{V}_{\mathrm{cc}}$ | MIN | TYP | MAX | UNIT |
| Dynamic |  |  |  |  |  |  |  |  |
| Turnon time $\mathrm{t}_{\text {ON }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ $C_{L}=35 \mathrm{pF},$ <br> See Figure 14 |  | $25^{\circ} \mathrm{C}$ | 1.8 V |  | 53 | 75 | ns |
|  |  |  | Full | $\begin{aligned} & 1.65 \mathrm{~V} \\ & \text { to } \\ & 1.96 \mathrm{~V} \end{aligned}$ |  |  | 80 |  |
|  |  |  | $25^{\circ} \mathrm{C}$ | 1.8 V |  | 24 | 35 |  |
| Turnoff time toff | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 14 | Full | $\begin{aligned} & 1.65 \mathrm{~V} \\ & \text { to } \\ & 1.96 \mathrm{~V} \end{aligned}$ |  |  | 40 | ns |
|  |  |  | $25^{\circ} \mathrm{C}$ | 1.8 V | 2 | 30 | 40 |  |
| Break-beforemake time <br> tbim | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}}=\mathrm{V}_{\mathrm{NO}}=\mathrm{V}_{\mathrm{CC}}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 15 | Full | $\begin{aligned} & 1.65 \mathrm{~V} \\ & \text { to } \\ & 1.96 \mathrm{~V} \end{aligned}$ | 1 |  | 50 | ns |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

### 6.11 Typical Characteristics



Figure 1. $r_{\text {on }}$ vs $V_{\text {com }}$
( $\mathrm{V}_{\mathrm{cc}}=1.65 \mathrm{~V}$ )


Figure 3. $\mathrm{r}_{\text {on }}$ vs $\mathrm{V}_{\text {com }}$
$\left(V_{C C}=2.7 \mathrm{~V}\right)$


Figure 5. $\mathrm{t}_{\mathrm{ON}}$ and $\mathrm{t}_{\mathrm{ofF}}$ vs Supply Voltage

$$
\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right)
$$



Figure 2. $\mathrm{r}_{\text {on }}$ vs $\mathrm{V}_{\text {com }}$
( $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ )


Figure 4. Charge Injection $\left(Q_{C}\right)$ vs $V_{C O M}$ ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )


Figure 6. Bandwidth

## Typical Characteristics (continued)



Figure 7. OFF Isolation


Figure 8. Crosstalk


Figure 9. Total Harmonic Distortion vs Frequency

## 7 Parameter Measurement Information



Figure 10. ON-State Resistance


OFF-State Leakage Current Channel OFF $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$

Figure 11. OFF-State Leakage Current
( $\left.I_{\text {NC(OFF) }}, I_{\text {NC(PWROFF) }}, I_{\text {NO(OFF) }}, I_{\text {NO(PWROFF) }}, I_{\text {COM(OFF) }}, I_{\text {COM(PWROFF) }}\right)$


ON-State Leakage Current Channel ON
$\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$

Figure 12. ON-State Leakage Current ( $\left.\mathrm{I}_{\mathrm{COM}(\mathrm{ON})}, \mathrm{I}_{\mathrm{NC}(\mathrm{ON})}, \mathrm{I}_{\mathrm{NO}(\mathrm{ON})}\right)$


Figure 13. Capacitance $\left.\mathrm{C}_{\mathrm{l}}, \mathrm{C}_{\mathrm{NC}(\mathrm{OFF})}, \mathrm{C}_{\mathrm{NO}(\mathrm{OFF})}, \mathrm{C}_{\mathrm{NC}(\mathrm{ON})}, \mathrm{C}_{\mathrm{NO}(\mathrm{ON})}\right)$


Figure 14. Turn-On ( $\mathrm{t}_{\mathrm{ON}}$ ) and Turn-Off Time ( $\mathrm{t}_{\mathrm{ofF}}$ )

(1) All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega$, $\mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.
(2) $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 15. Break-Before-Make Time ( $\mathrm{t}_{\mathrm{BBM}}$ )


Channel ON: NC to COM $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{CC}}$ or GND

Figure 16. Bandwidth (BW)


Channel OFF: NC to COM
$\mathrm{V}_{\mathrm{l}}=\mathrm{V}_{\mathrm{CC}}$ or GND

Network Analyzer Setup
Source Power $=0 \mathrm{dBm}$ (632-mV P-P at 50- $\Omega$ load) DC Bias $=350 \mathrm{mV}$

Figure 17. OFF Isolation ( $\mathrm{O}_{\text {Iso }}$ )


Channel ON: NC to COM Channel OFF: NO to COM $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$ or GND

## Network Analyzer Setup

Source Power $=0 \mathrm{dBm}$ ( $632-\mathrm{mV}$ P-P at $50-\Omega$ load) DC Bias $=350 \mathrm{mV}$

Figure 18. Crosstalk ( $\mathrm{X}_{\text {TALK }}$ )


$$
\begin{aligned}
& \mathrm{V}_{\mathrm{GEN}}=0 \text { to } \mathrm{V}_{\mathrm{CC}} \\
& \mathrm{R}_{\mathrm{GEN}}=0 \\
& \mathrm{C}_{\mathrm{L}}=1 \mathrm{nF} \\
& \mathrm{Q}_{\mathrm{C}}=\mathrm{C}_{\mathrm{L}} \times \Delta \mathrm{V}_{\mathrm{COM}} \\
& \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}}
\end{aligned}
$$

A. All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega$, $\mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.
B. $C_{L}$ includes probe and jig capacitance.

Figure 19. Charge Injection ( $Q_{C}$ )

| Channel ON: COM to NO | $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ | $\mathrm{R}_{\mathrm{L}}=600 \Omega$ |
| :--- | :--- | :--- |
| $\mathrm{~V}_{\text {SOURCE }}=\mathrm{V}_{\mathrm{CC}} \mathrm{P}-\mathrm{P}$ | Source Signal $=20 \mathrm{~Hz}$ to 20 kHz | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |


A. $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 20. Total Harmonic Distortion (THD)

## 8 Detailed Description

### 8.1 Overview

The TS3A24159 is a 2-channel single-pole double-throw (SPDT) bidirectional analog switch that is designed to operate from 1.65 V to 3.6 V . It offers low ON -state resistance and excellent ON -state resistance matching with the break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another. The device has excellent total harmonic distortion (THD) performance, low ON-state resistence, and consumes very low power. These are some of the features make this device suitable for a variety of markets and many different applications.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

The TS3A24159 device is bidirectional with two single-pole, double-throw switches. Each of the two switches are controlled independently by two digital signals.

### 8.4 Device Functional Modes

Table 1. Function Table

| IN | NC TO COM, <br> COM TO NC | NO TO COM, <br> COM TO NO |
| :---: | :---: | :---: |
| L | ON | OFF |
| H | OFF | ON |

## 9 Application and Implementation

## NOTE

Information in the following applications sections is not part of the Tl component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The switch of the TS3A23159 device is bidirectional. Hence, NO, NC and COM pins can be used as both inputs or outputs.

### 9.2 Typical Application



### 9.2.1 Design Requirements

Ensure that all of the signals passing through the switch are with in the specified ranges to ensure proper performance.

Table 2. Design Parameters

|  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply Voltage | 1.65 | 3.6 | V |
| $\mathrm{V}_{\mathrm{NC}}$ <br> $\mathrm{V}_{\mathrm{NO}}$ <br> $V_{\text {COM }}$ | Signal Voltage | 0 | $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{V}_{\text {IN }}$ | Digital Input Voltage | 0 | $\mathrm{V}_{\mathrm{CC}}$ | V |

### 9.2.2 Detailed Design Procedure

The TS3A23159 device can be properly operated without any external components. However, it is recommended that unused pins must be connected to ground through a $50-\Omega$ resistor to prevent signal reflections back into the device. It is also recommended that the digital control pins (IN1 and IN2) be pulled up to VCC or down to GND to avoid undesired switch positions that could result from the floating pin.
Select the appropriate supply voltage to cover the entire voltage swing of the signal passing through the switch because the TS3A23159 input/output signal swing through NO and COM are dependant of the supply voltage VCC.

### 9.2.3 Application Curve



Figure 21. $\mathrm{r}_{\mathrm{ON}}$ vs $\mathrm{V}_{\text {com }}$

## 10 Power Supply Recommendations

- Proper power-supply sequencing is recommended for all CMOS devices.
- Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the device.
- Always sequence VCC on first, followed by NO or COM.
- Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the VCC supply to other components.
- A $0.1-\mu \mathrm{F}$ capacitor, connected from VCC to GND, is adequate for most applications.


## 11 Layout

### 11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended. Bypass capacitors must be used on power supplies. Short trace lengths should be used to avoid excessive loading.

### 11.2 Layout Example



Figure 22. Layout Example

## 12 Device and Documentation Support

### 12.1 Documentation Support

### 12.1.1 Related Documentation

For related documentation see the following: Implications of Slow or Floating CMOS Inputs, SCBA004

### 12.2 Community Resources

TI E2E ${ }^{\text {TM }}$ support forums are an engineer's go-to source for fast, verified answers and design help - straight from the experts. Search existing answers or ask your own question to get the quick design help you need.
Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect Tl's views; see Tl's Terms of Use.

### 12.3 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

### 12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.5 Glossary

SLYZ022 - TI Glossary.
This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status <br> (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <br> (2) | Lead/Ball Finish <br> (6) | MSL Peak Temp <br> (3) | Op Temp ( ${ }^{\circ} \mathrm{C}$ ) | Device Marking <br> (4/5) | Samples |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS3A24159DGSR | ACTIVE | VSSOP | DGS | 10 | 2500 | Green (RoHS \& no $\mathrm{Sb} / \mathrm{Br}$ ) | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | (L8Q, L8R) | Samples |
| TS3A24159DGSRG4 | ACTIVE | VSSOP | DGS | 10 | 2500 | $\begin{aligned} & \text { Green (RoHS } \\ & \& \text { no } \mathrm{Sb} / \mathrm{Br}) \end{aligned}$ | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | (L8Q, L8R) | Samples |
| TS3A24159DRCR | ACTIVE | VSON | DRC | 10 | 3000 | Green (RoHS \& no $\mathrm{Sb} / \mathrm{Br}$ ) | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | zWS | Samples |
| TS3A24159DRCRG4 | ACTIVE | VSON | DRC | 10 | 3000 | Green (RoHS \& no $\mathrm{Sb} / \mathrm{Br}$ ) | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | zWS | Samples |
| TS3A24159YZPR | ACTIVE | DSBGA | YZP | 10 | 3000 | Green (RoHS \& no $\mathrm{Sb} / \mathrm{Br}$ ) | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | L87 | Samples |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
${ }^{(2)}$ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of $<=1000$ ppm threshold. Antimony trioxide based flame retardants must also meet the $<=1000$ ppm threshold requirement.
${ }^{(3)}$ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
${ }^{(4)}$ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
${ }^{(5)}$ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a " $\sim$ " will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
${ }^{(6)}$ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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## TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> Diameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> $\mathbf{W 1}(\mathbf{m m})$ | A0 <br> $(\mathbf{m m})$ | B0 <br> $(\mathbf{m m})$ | K0 <br> $(\mathbf{m m})$ | P1 <br> $(\mathbf{m m})$ | W <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS3A24159DGSR | VSSOP | DGS | 10 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TS3A24159DRCR | VSON | DRC | 10 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TS3A24159YZPR | DSBGA | YZP | 10 | 3000 | 178.0 | 9.2 | 1.49 | 1.99 | 0.63 | 4.0 | 8.0 | Q2 |


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS3A24159DGSR | VSSOP | DGS | 10 | 2500 | 358.0 | 335.0 | 35.0 |
| TS3A24159DRCR | VSON | DRC | 10 | 3000 | 367.0 | 367.0 | 35.0 |
| TS3A24159YZPR | DSBGA | YZP | 10 | 3000 | 220.0 | 220.0 | 35.0 |



## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.


NOTES: (continued)
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.


SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL SCALE:10X

NOTES: (continued)
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.


NOTES: (continued)
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
EXPOSED PAD 11:
80\% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

NOTES: (continued)
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.


NOTES: (continued)
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.

For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).


SOLDER PASTE EXAMPLE BASED ON 0.1 mm THICK STENCIL SCALE:30X

NOTES: (continued)
4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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